TUNNEL OXIDE PASSIVATING ELECTRON CONTACTS AS FULL-AREA REAR EMITTER OF HIGH-EFFICIENCY P-TYPE SILICON SOLAR CELLS

Armin Richter\textsuperscript{a}, Jan Benick\textsuperscript{a}, Ralph Müller\textsuperscript{a,b}, Frank Feldmann\textsuperscript{a,b}, Christian Reichel\textsuperscript{a}, Martin Hermle\textsuperscript{c}, Stefan W. Glunz\textsuperscript{a,b}

\textsuperscript{a} Fraunhofer Institute for Solar Energy Systems (ISE), Heidenhofstrasse 2, 79110 Freiburg, Germany
\textsuperscript{b} Department of Sustainable Systems Engineering, Albert Ludwig University of Freiburg, Georges-Köhler-Allee 103, D-79110 Freiburg, Germany

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